ERRATA

Erratum: "Microstructural evolution and nanocrystal formation in Pb^+-implanted $ZrSiO_4$ single crystals" [J. Appl. Phys. 94, 5695 (2003)]

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Figure 5(b). Labels are ordered incorrectly. The order, from the most intense to the less intense, should be as follows: $\alpha_i = 0.2°$, $\alpha_i = 0.75°$, $\alpha_i = 1.5°$, and $\alpha_i = 5.0°$.

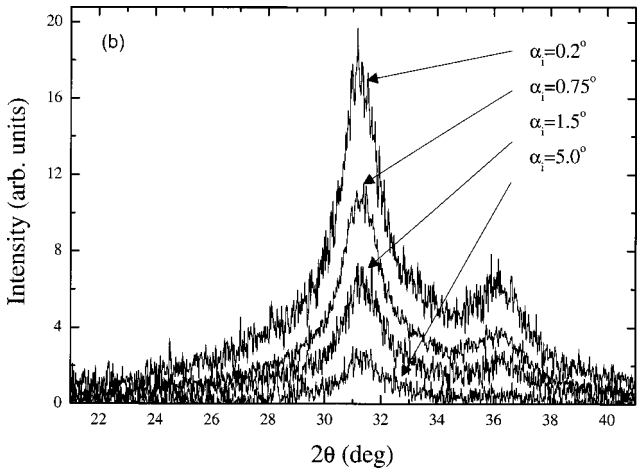

FIG. 5. (a) Intensity of the (111)/200) Pb peaks in the sample irradiated at 10^{17} Pb ions/cm^2 for an incident angle of 0.5°. Note the contribution due to the amorphous zircon layer. (b) Intensity of the (111)/(200) Pb peaks as a function of the incident angle, α_i.

